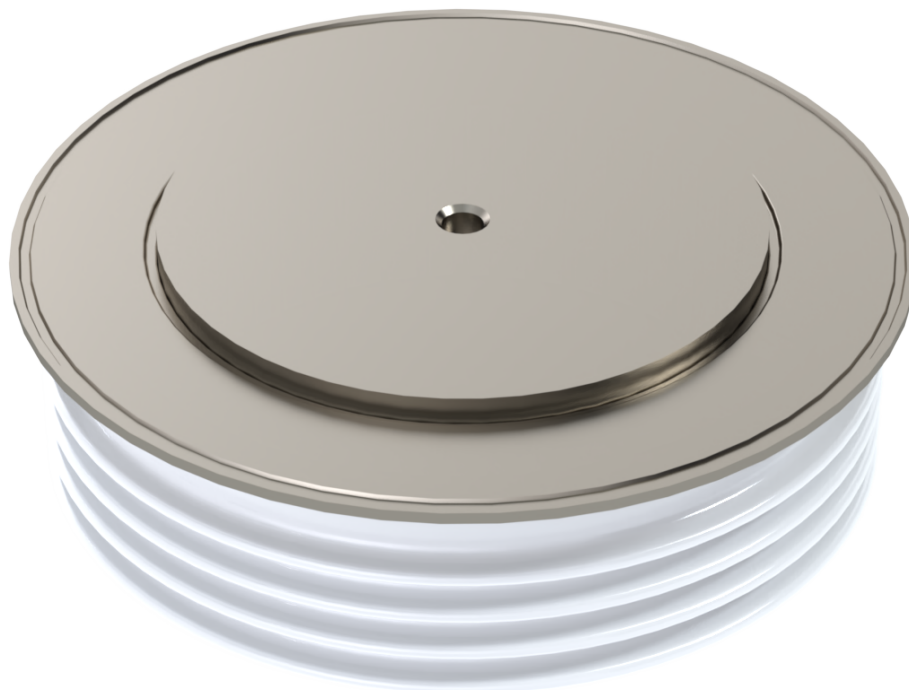


**Rectifier
Diode
Type SA18ZP4767J0**

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Date: April, 2020
Data Sheet Issue: 1



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(Please quote 12 to 15 digit code as below)

SA	18	ZP	4767	J	0	
-	Voltage Code	Outline Code	Current code	Type code	Special code	Optional code

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Absolute Maximum Ratings

VOLTAGE RATINGS		MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1900	V
V_{RDC}	Maximum reverse D.C. Voltage, (note 1)	1125	V
note 1)	De-Rating factor of 0.13% per °C is applicable for T_j below 25°C		

OTHER RATINGS		MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_{sink} = 55^\circ\text{C}$, (note 1)	4755	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink} = 100^\circ\text{C}$, (note 1)	3475	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink} = 100^\circ\text{C}$, (note 2)	2015	A
$I_{F(RMS)}$	Nominal RMS forward current, $T_{sink} = 25^\circ\text{C}$ (note 1)	8615	A
$I_{f(d.c.)}$	D.C. forward current, $T_{sink} = 25^\circ\text{C}$ (note 3)	7425	A
I_{FSM}	Peak non-repetitive surge current $t_p = 10\text{ms}$, $V_{RM} = 60\%V_{RRM}$, (note 4)	38.0	kA
I_{FSM2}	Peak non-repetitive surge current $t_p = 10\text{ms}$, $V_{RM} \leq 10\text{V}$, (note 4)	41.8	kA
I^2t	I^2t capacity for fusing $t_p = 10\text{ms}$, $V_{RM} = 60\%V_{RRM}$, (note 4)	$7.22 \cdot 10^6$	A^2s
I^2t	I^2t capacity for fusing $t_p = 10\text{ms}$, $V_{RM} \leq 10\text{V}$, (note 4)	$8.74 \cdot 10^6$	A^2s
T_{jop}	Operating temperature range	-40 to +175	°C
T_{stg}	Storage temperature range	-40 to +175	°C
note 1)	Double-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 2)	Cathode-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 3)	Double-side cooled.		
note 4)	Half-sinewave, 175°C T_j initial.		

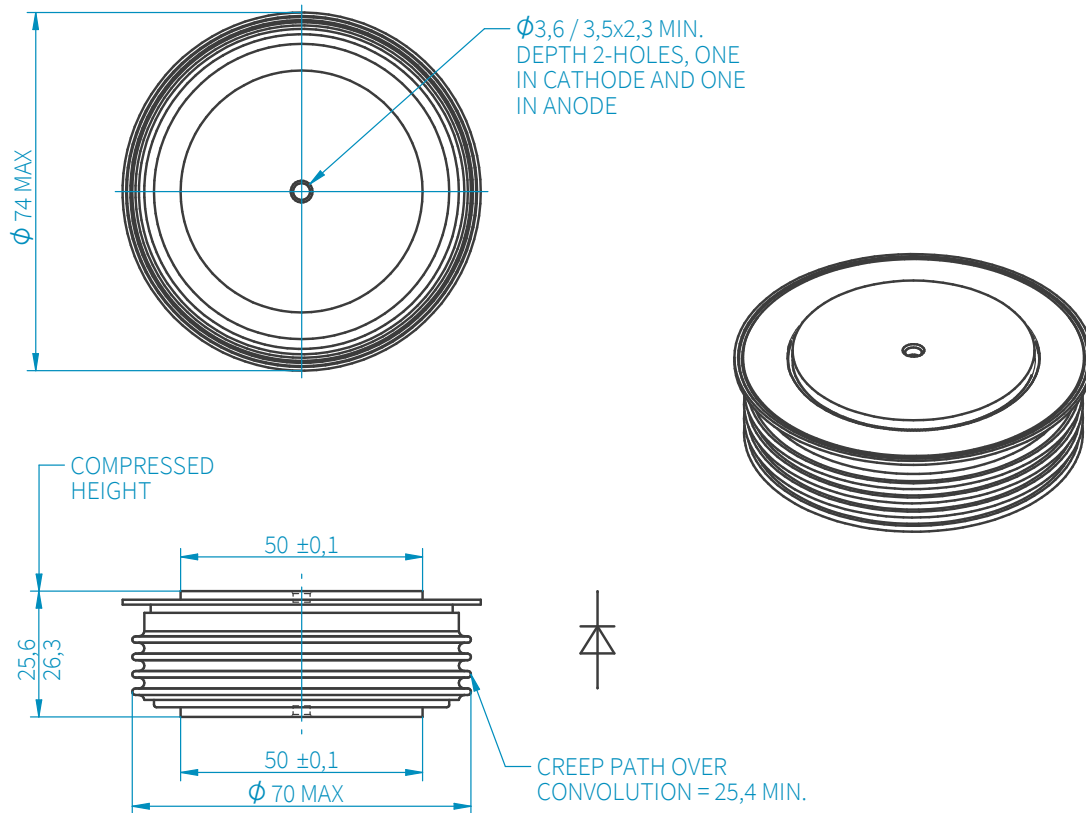
Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V _{FM}	Maximum peak forward voltage	I _{FM} =3000A	-	-	1.05	V
		I _{FM} =8000A	-	-	1.50	V
V _{T0}	Threshold Voltage		-	-	0.827	V
r _T	Slope resistance		-	-	0.083	mΩ
I _{R_{RM}}	Peak reverse current	Rated V _{RRM} , T _j = 25°C	-	-	5	mA
		Rated V _{RRM} , T _j = T _{jmax}	-	-	50	mA
Q _{rr}	Recovered charge		-	3800	4100	μC
Q _{ra}	Recovered charge, 50% Chord	I _{FM} = 1000A, t _p = 1000μs,	-	2250	-	μC
I _{rm}	Reverse recovery current	di/dt = 10A/μs, V _R = 100V	-	172	-	A
t _{rr}	Reverse recovery time, 50% Chord		-	26	-	μs
R _{thJK}	Thermal resistance, junction to heatsink	Double side cooled	-	-	14.0	K/kW
		Anode side cooled	-	-	26.5	K/kW
		Cathode side cooled	-	-	30.0	K/kW
F	Mounting force	note 2)	25	-	31	kN
W _t	Weight		-	530	-	g
note 1)	Unless otherwise indicated T _j = 175°C					
note 2)	For other clamp forces consult factory					

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